PMEG4050ETP



40 V, 5 A low VF MEGA Schottky barrier rectifier
Rev. 1 — 10 October 2011 Pro

Product data sheet

1. **Product profile**

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD128 small and flat lead Surface-Mounted Device (SMD) plastic package.

1.2 Features and benefits

- Average forward current: I_{F(AV)} ≤ 5 A
- Reverse voltage: V_R ≤ 40 V
- Low forward voltage
- High power capability due to clip-bonding technology
- Small and flat lead SMD plastic package
- AEC-Q101 qualified
- High temperature T_i ≤ 175 °C

1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Reverse polarity protection
- Low power consumption applications
- High temperature applications

1.4 Quick reference data

Quick reference data Table 1.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$I_{F(AV)}$	average forward current	square wave; δ = 0.5; f = 20 kHz; T _{sp} ≤ 155 °C	-	-	5	Α
V_R	reverse voltage	T _j = 25 °C	-	-	40	V
V _F	forward voltage	I _F = 5 A; T _j = 25 °C	-	430	490	mV
I _R	reverse current	$T_j = 25 ^{\circ}\text{C}; V_R = 40 \text{V}$	-	60	300	μΑ



2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode[1]		. 54 -
2	Α	anode	1 2	1
			SOD128	

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PMEG4050ETP	-	plastic surface-mounted package; 2 leads	SOD128

4. Marking

Table 4. Marking codes

Type number	Marking code
PMEG4050ETP	C4

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_R	reverse voltage	T _j = 25 °C		-	40	V
I _{F(AV)}	average forward current	square wave; δ = 0.5; f = 20 kHz; T _{amb} ≤ 15 °C	<u>[1]</u>	-	5	А
		square wave; δ = 0.5; f = 20 kHz; T _{sp} ≤ 155 °C		- 5	Α	
I _{FSM}	non-repetitive peak forward current	square wave; $t_p = 8 \text{ ms}$; $T_{j(init)} = 25 \text{ °C}$		-	70	Α
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[2][3]	-	750	mW
			[4][3]	-	1250	mW
			[1][3]	-	2500	mW
Tj	junction temperature			-	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C

^[1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al₂O₃, standard footprint.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance	in free air	[1][2][3]	-	-	200	Wnit K/W K/W K/W
	from junction to ambient		[1][4][3]	-	-	120	K/W
	ambient		[1][5][3]	-	-	60	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		[6]	-	-	12	K/W

^[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[3] Reflow soldering is the only recommended soldering method.

^[4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[3] Reflow soldering is the only recommended soldering method.

^[4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

^[5] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.

^[6] Soldering point of cathode tab.

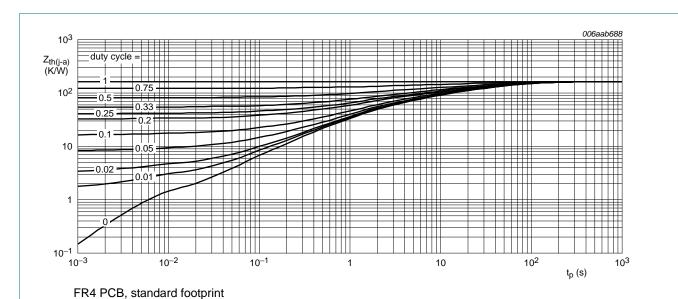


Fig 1. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

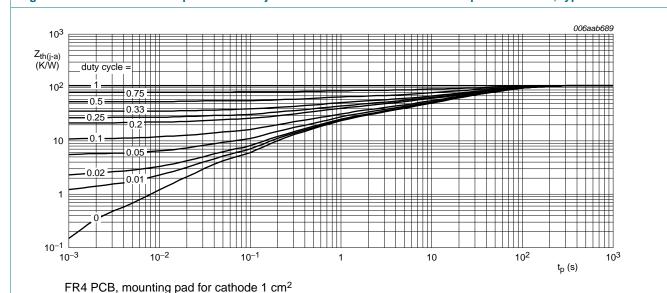
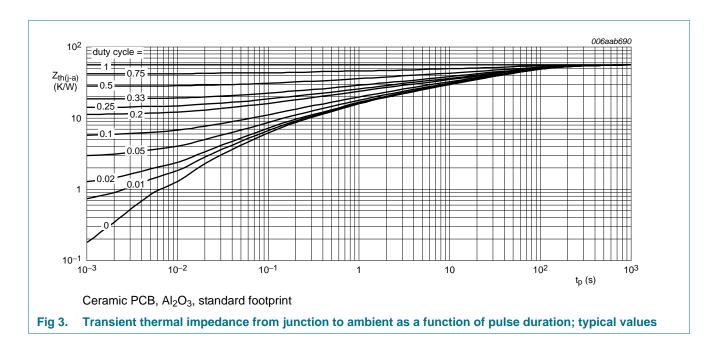


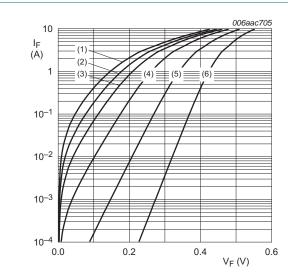
Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



7. Characteristics

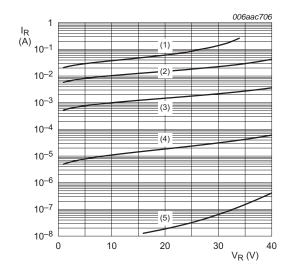
Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _F forward voltage	forward voltage	$I_F = 0.1 \text{ A}; T_j = 25 ^{\circ}\text{C}$	-	270	310	mV
		I _F = 1 A; T _j = 25 °C	-	340	390	mV
		I _F = 5 A; T _j = 25 °C	-	430	490	mV
		I _F = 5 A; T _j = 125 °C	-	340	390	mV
I _R rev	reverse current	$V_R = 10 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	10	-	μA
		$V_R = 40 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	60	300	μA
		$V_R = 10 \text{ V}; T_j = 125 ^{\circ}\text{C}$	-	10	-	mV μA
		$V_R = 40 \text{ V}; T_j = 125 ^{\circ}\text{C}$	-	42	-	mA
C _d	diode capacitance	$V_R = 1 \text{ V; } f = 1 \text{ MHz; } T_j = 25 ^{\circ}\text{C}$	-	600	-	pF
		$V_R = 10 \text{ V; } f = 1 \text{ MHz; } T_j = 25 \text{ °C}$	-	220	-	pF



- (1) $T_i = 175 \, ^{\circ}C$
- (2) $T_j = 150 \, ^{\circ}\text{C}$
- (3) $T_i = 125 \, ^{\circ}C$
- (4) $T_j = 85 \, ^{\circ}C$
- (5) $T_j = 25 \,{}^{\circ}\text{C}$
- (6) $T_j = -40 \, ^{\circ}C$

Fig 4. Forward current as a function of forward voltage; typical values



- (1) $T_i = 150 \, ^{\circ}\text{C}$
- (2) $T_i = 125 \, ^{\circ}C$
- (3) $T_i = 85 \, ^{\circ}C$
- (4) $T_j = 25 \, ^{\circ}C$
- (5) $T_j = -40 \, ^{\circ}\text{C}$

Fig 5. Reverse current as a function of reverse voltage; typical values

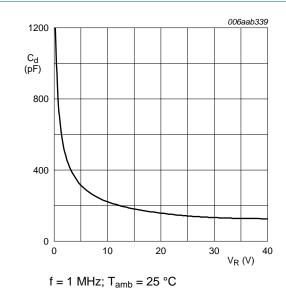
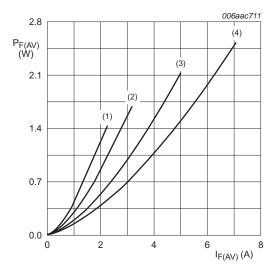
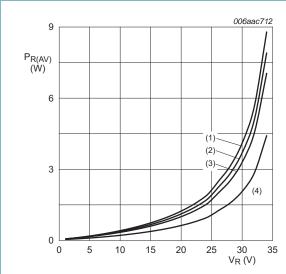


Fig 6. Diode capacitance as a function of reverse voltage; typical values



- $T_i = 175 \,{}^{\circ}\text{C}$
- (1) $\delta = 0.1$
- (2) $\delta = 0.2$
- (3) $\delta = 0.5$
- (4) $\delta = 1.0$

Fig 7. Average forward power dissipation as a function of average forward current; typical values



 $T_i = 150 \, ^{\circ}C$

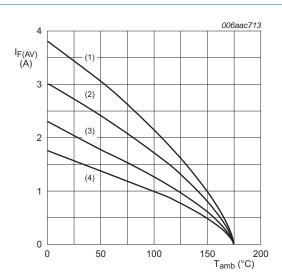
 $(1) \delta = 1.0$

(2) $\delta = 0.9$

(3) $\delta = 0.8$

(4) $\delta = 0.5$

Fig 8. Average reverse power dissipation as a function of reverse voltage; typical values



FR4 PCB, standard footprint

T_i = 175 °C

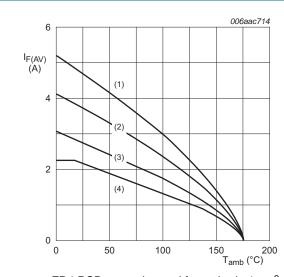
(1) $\delta = 1.0 (DC)$

(2) $\delta = 0.5$; f = 20 kHz

(3) $\delta = 0.2$; f = 20 kHz

(4) $\delta = 0.1$; f = 20 kHz

Fig 9. Average forward current as a function of ambient temperature; typical values



FR4 PCB, mounting pad for cathode 1 \mbox{cm}^2

T_i = 175 °C

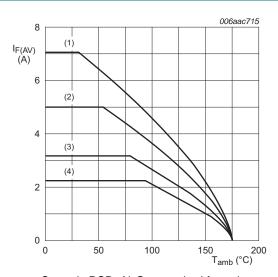
(1) $\delta = 1.0$

(2) $\delta = 0.9$

(3) $\delta = 0.8$

 $(4) \delta = 0.5$

Fig 10. Average forward current as a function of ambient temperature; typical values



Ceramic PCB, Al₂O₃, standard footprint

T_i = 175 °C

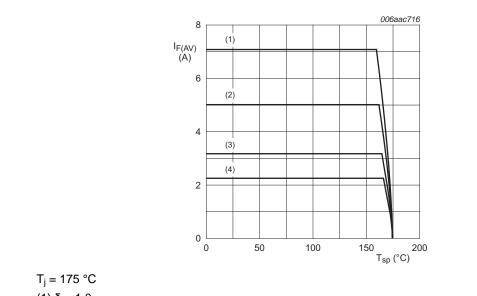
(1) $\delta = 1.0$ (DC)

(2) $\delta = 0.5$; f = 20 kHz

(3) $\delta = 0.2$; f = 20 kHz

(4) $\delta = 0.1$; f = 20 kHz

Fig 11. Average forward current as a function of ambient temperature; typical values



(1) $\delta = 1.0$

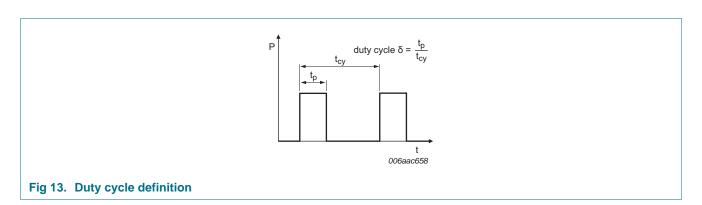
(2) $\delta = 0.9$

(3) $\delta = 0.8$

(4) $\delta = 0.5$

Fig 12. Average forward current as a function of solder point temperature; typical values

8. Test information

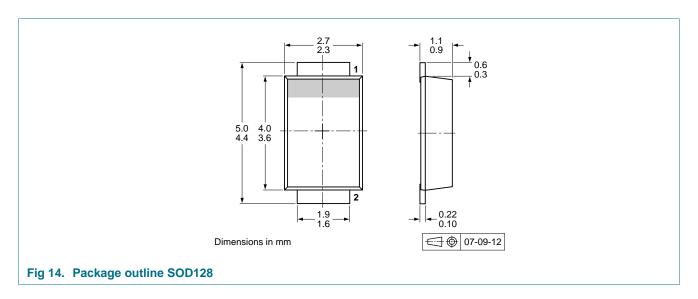


The current ratings for the typical waveforms as shown in figures $\underline{9}$, $\underline{10}$, $\underline{11}$ and $\underline{12}$ are calculated according to the equations: $I_{F(AV)} = I_M \times \delta$ with I_M defined as peak current, $I_{RMS} = I_{F(AV)}$ at DC, and $I_{RMS} = I_M \times \sqrt{\delta}$ with I_{RMS} defined as RMS current.

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

9. Package outline



10. Packing information

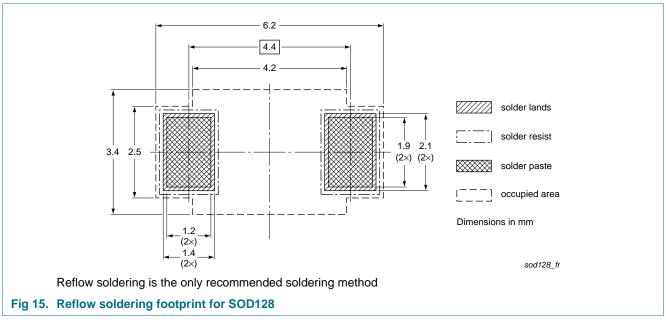
Table 8. Ordering information

The indicated -xxx are the last three digits of the 12NC ordering code. [1]

Type number	Package	Description	Packing quantity
			3000
PMEG4050ETP	SOD128	4 mm pitch, 12 mm tape and reel	-115

[1] For further information and the availability of packing methods, see 14 "Contact information".

11. Soldering



PMEG4050ETP

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12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG4050ETP v.1	20111010	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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15. Contents

1	Product profile	1
1.1	General description	1
1.2	Features and benefits	1
1.3	Applications	1
1.4	Quick reference data	1
2	Pinning information	2
3	Ordering information	2
4	Marking	2
5	Limiting values	3
6	Thermal characteristics	
7	Characteristics	5
8	Test information	8
8.1	Quality information	8
9	Package outline	9
10	Packing information	9
11	Soldering	9
12	Revision history1	0
13	Legal information1	1
13.1	Data sheet status	1
13.2	Definitions1	1
13.3	Disclaimers	
13.4	Trademarks1	2
14	Contact information 1	2

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